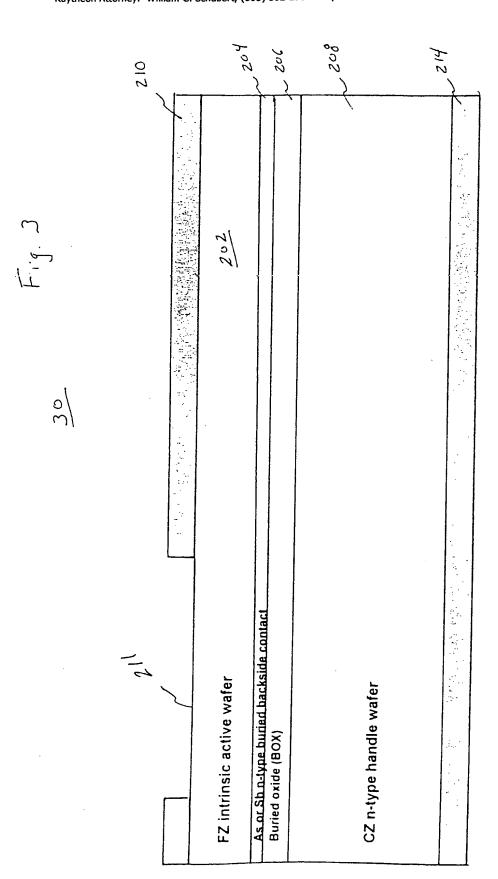
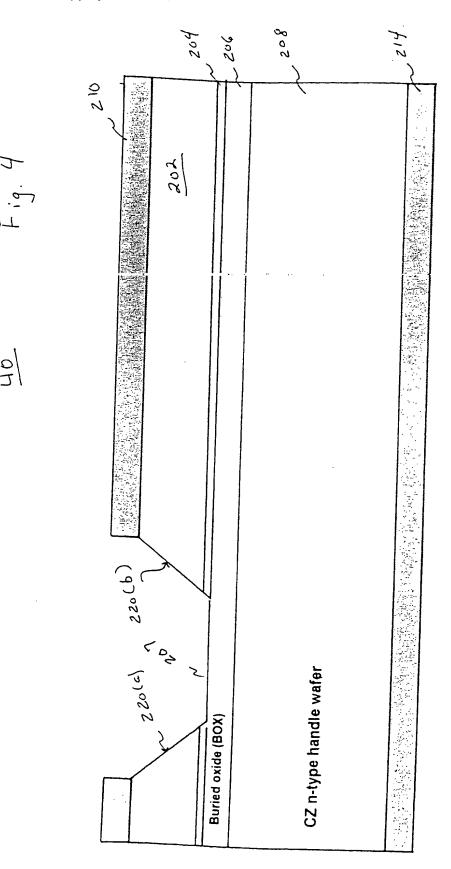
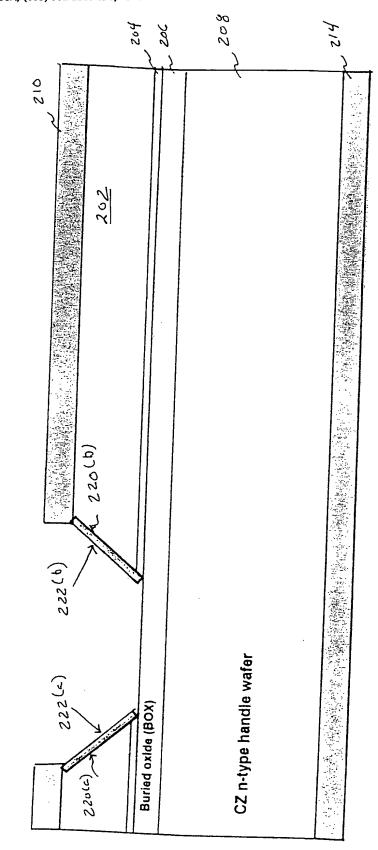


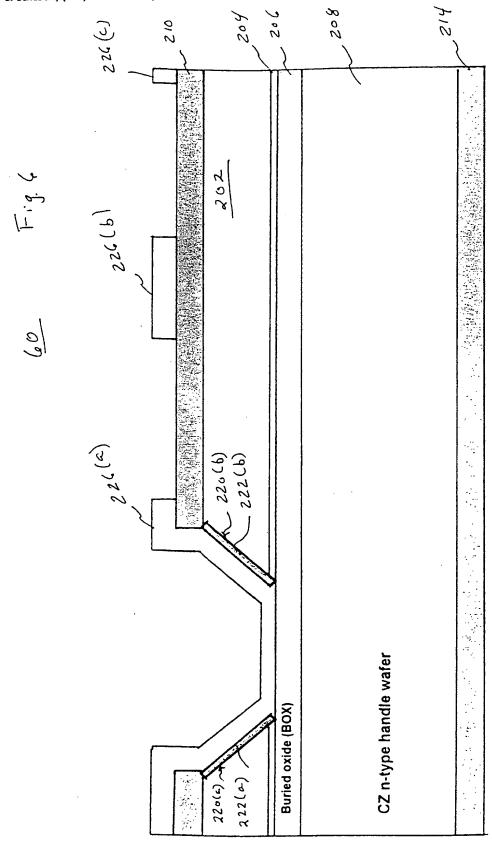
	. 212	<u> </u>	7	402	206	, 2007)		412	216	· }
Z 20 Fig. Z				202						
	717	2	のである。 本語の経験機能をある。 1980年の1980	FZ intrinsic active wafer	As or Sb n-type buried backside contact Buried oxide (BOX)		CZ n-type handle wafer			

Title: PIN detector apparatus and method of fabrication
First named inventor: FLETCHER, Christopher L. Attorney Docket No. 03W085
Raytheon Attorney: William C. Schubert, (805) 562-2108 telephone

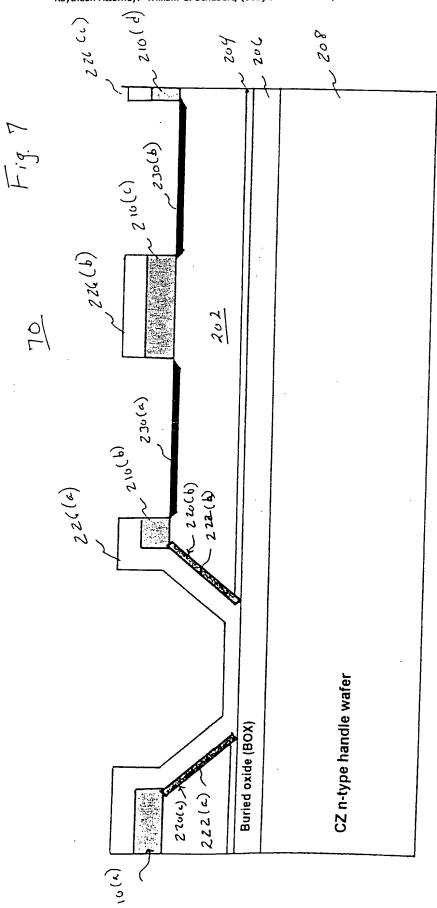


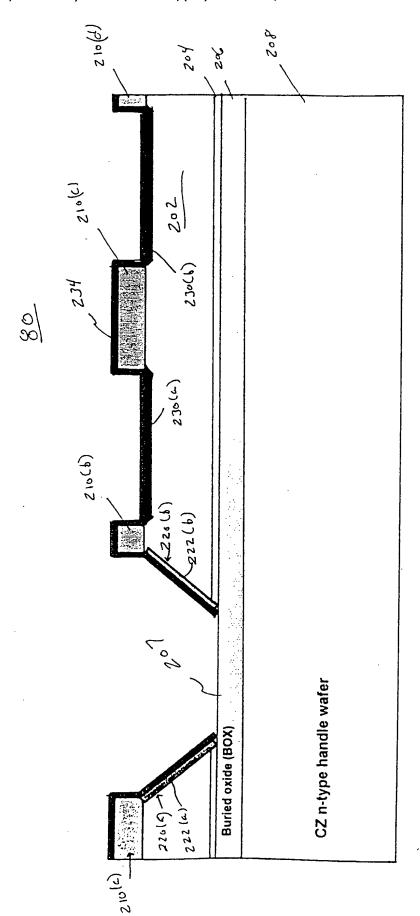


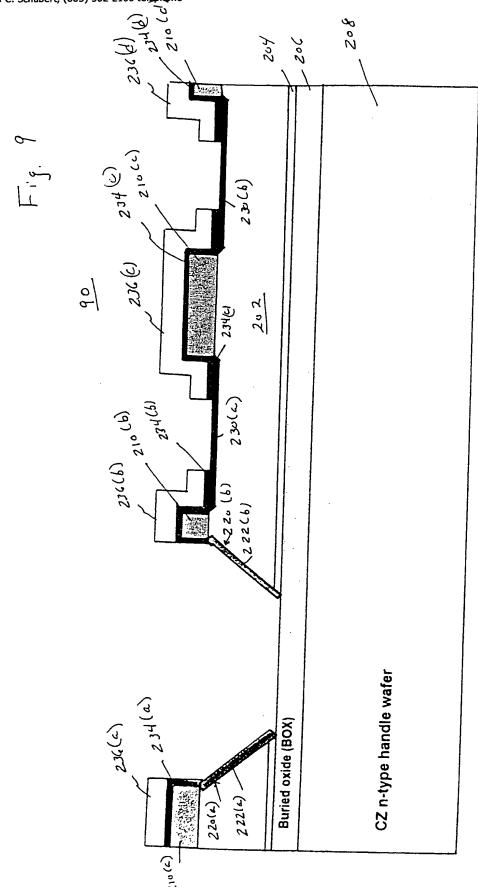


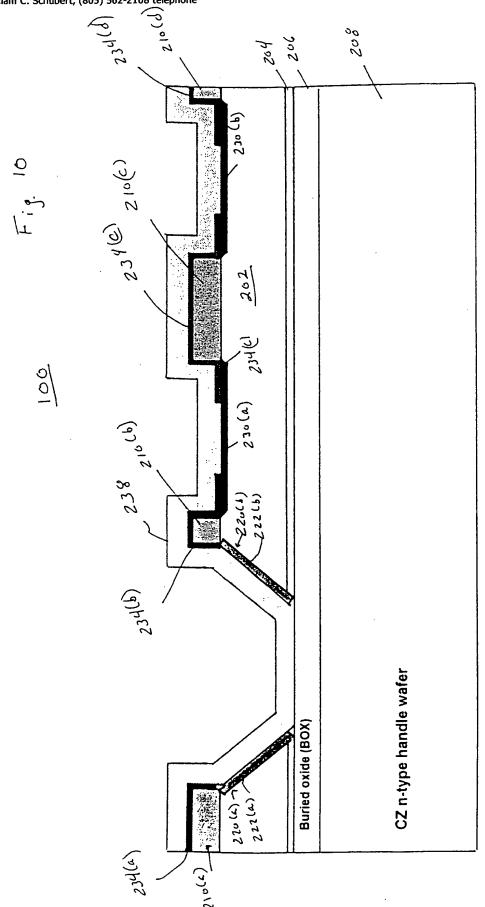


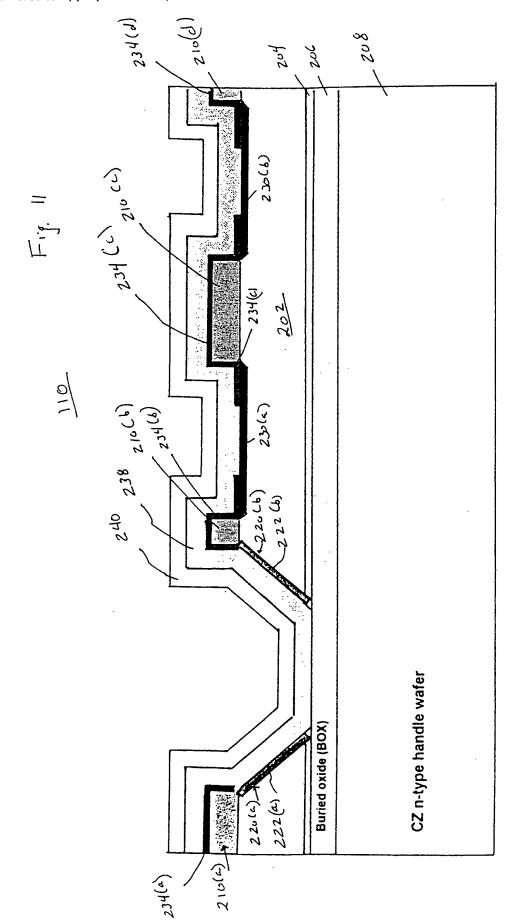
Title: PIN detector apparatus and method of fabrication First named inventor: FLETCHER, Christopher L. Attorney Docket No. 03W085 Raytheon Attorney: William C. Schubert, (805) 562-2108 telephone

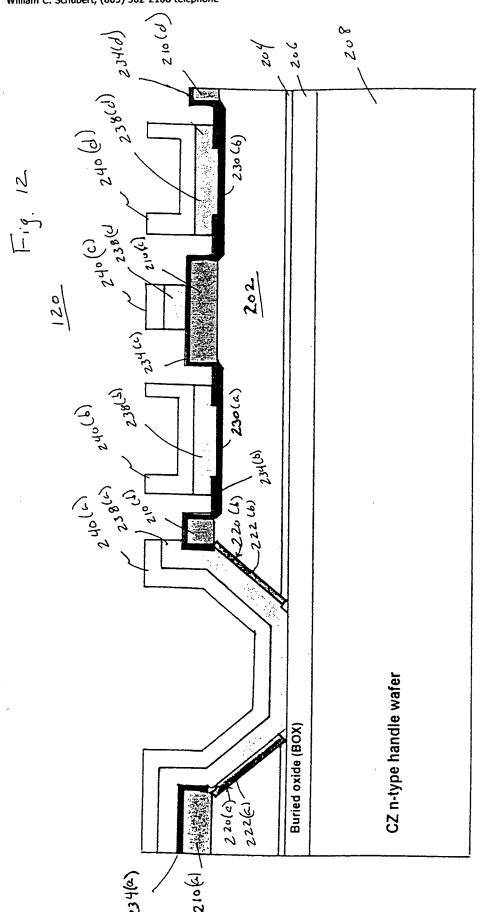




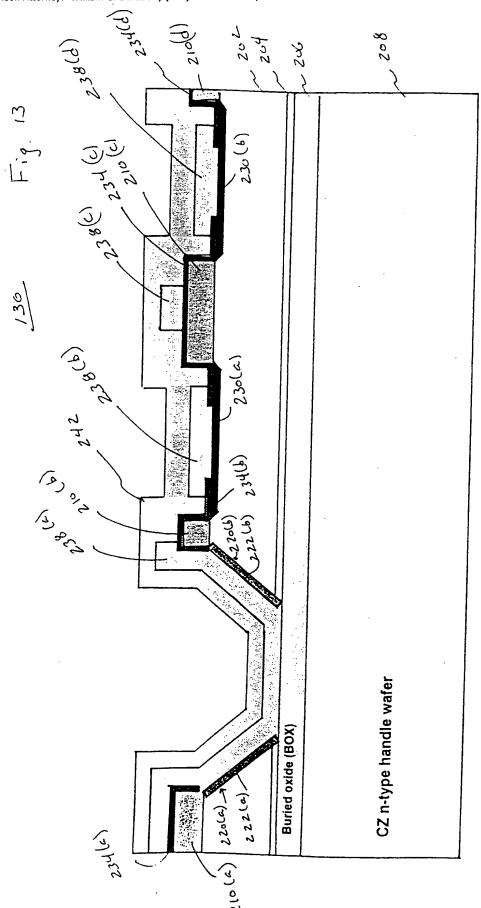


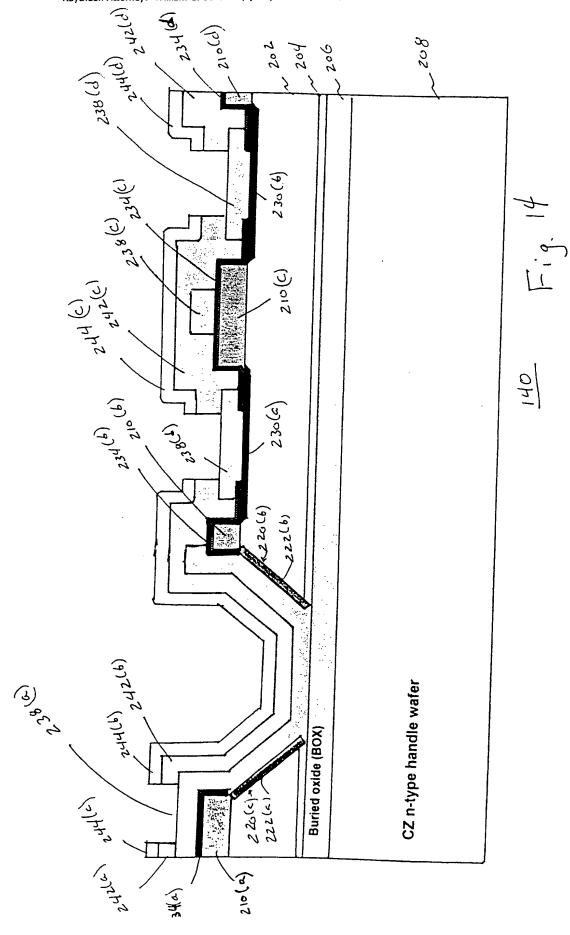


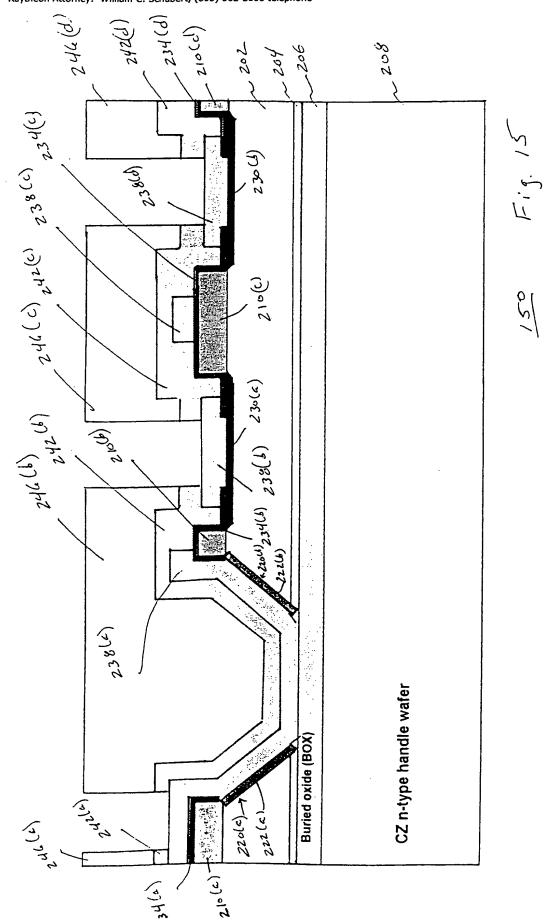




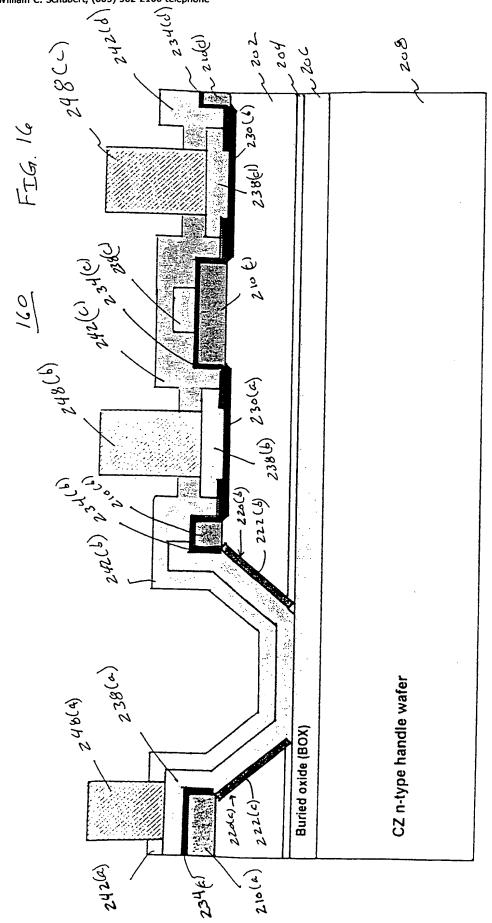
Title: PIN detector apparatus and method of fabrication First named inventor: FLETCHER, Christopher L. Attorney Docket No. 03W085 Raytheon Attorney: William C. Schubert, (805) 562-2108 telephone





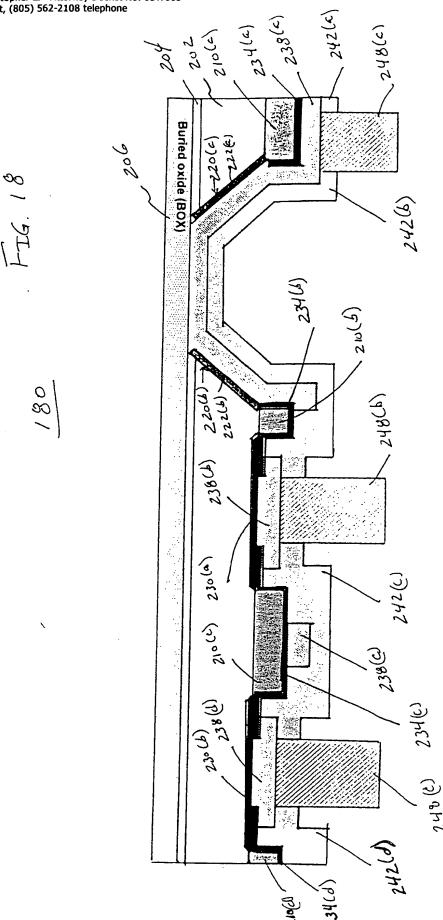


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Title: PIN detector apparatus and method of fabrication
First named inventor: FLETCHER, Christopher L. Attorney Docket No. 03W085
Raytheon Attorney: William C. Schubert, (805) 562-2108 telephipne CZ n-type handle wafer Buried oxide (BOX) 2226 20 (a) 220(6) 230(4) 234(6) 238(6) 242(6) (2)012 234(8)

Fig. 17



234(4)